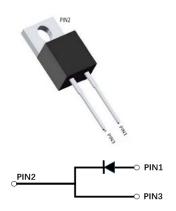






Silicon Carbide Schottky Diode

V_{RRM}	1700V
I _{F (135°C)}	18A
Q _C	143nC



Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

 Package: TO-220AC
 Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free

• Terminals: Tin plated leads

• Polarity: As marked

■Maximum Ratings (T_C =25 $^{\circ}$ C Unless otherwise specified)

PARAMTETER	SYMBOL	UNIT	VALUE
Device marking code			D117010PG1
Reverse voltage (repetitive peak) @ T _j =25°C	V_{RRM}	V	1700
Reverse voltage (Surge Peak) @ T _j =25°C	V_{RSM}	V	1700
Reverse voltage (DC) @ T _j =25°C	V _{DC}	V	1700
Continuous forward current @ T _C =25°C		А	36
Continuous forward current @ T _c =135°C	I _F		18
Continuous forward current @ T _C =160°C			10
Non-repetitive peak forward surge current @ T _C =25°C, tp=10ms, Half Sine Wave	I _{FSM}	А	72
Power Dissipation@ T _C =25°C	В	w	223
Power Dissipation@ T _C =110°C	Ртот		97
i²t Value@ T _C =25°C ,tp=10ms	∫ i²dt	A ² S	25
Operating junction and Storage temperature range	T_{j} , T_{stg}	°C	-55 to +175





■Electrical Characteristics

PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.	
Forward voltage drop	V _F	V	I _F =10A, T _j =25°C	1.4	1.55	
			I _F =10A, T _j =175°C	2.2	-	
Povorce leakage current	I _R µ			V _R =1700V, T _j =25°C	3	18
Reverse leakage current		μA	V _R =1700V, T _j =175°C	10	-	
Total capacitive charge	Q _C	nC	V_R =1700V, T_j =25°C, Q_C = $\int_0^{VR}C(V)dV$	143	-	
	C p			V _R =0V, f=1MHZ	1258	-
Total capacitance		pF	V _R =800V, f=1MHZ	64	-	
			V _R =1700V, f=1MHZ	63	-	
Capacitance Stored Energy	Ec	μJ	V _R =1700V	73	-	

■Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	R _{eJ-C}	°C W	0.67

■Typical Characteristics

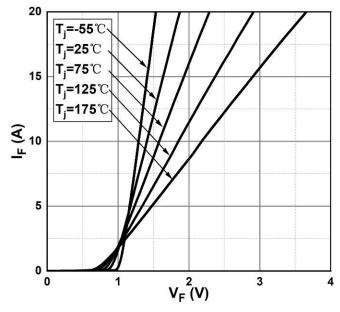


Figure 1. Forward Characteristics

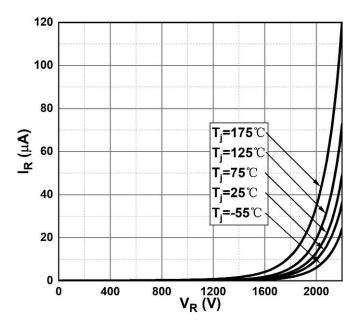
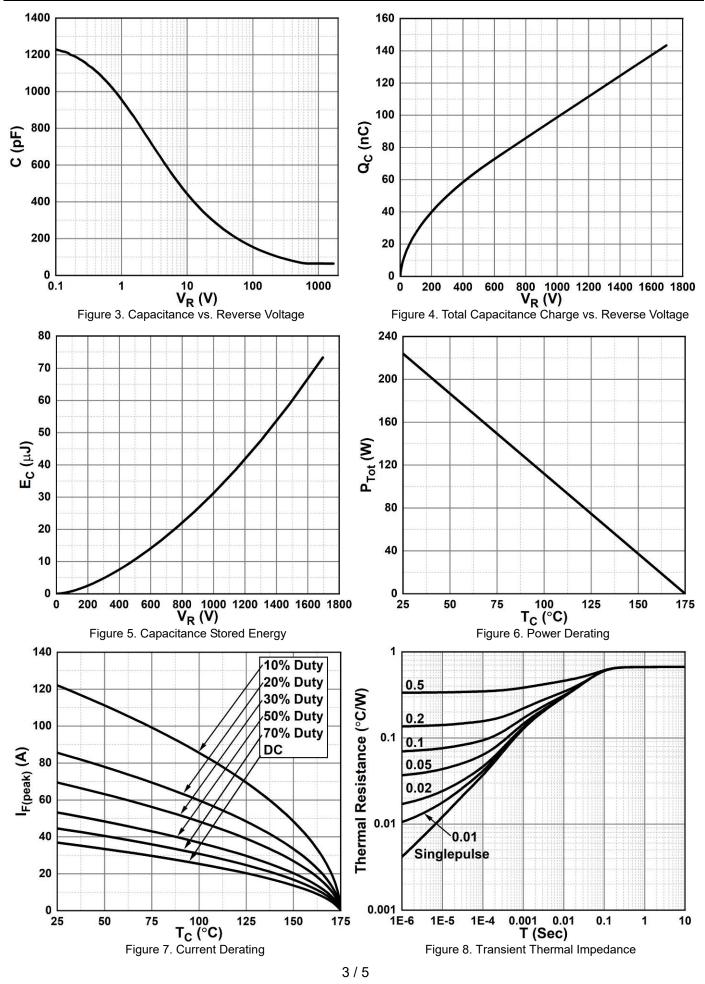


Figure 2. Reverse Characteristics



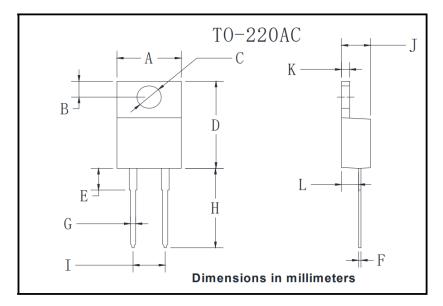








■Outline Dimensions



TO-220AC				
Dim	Min	Max		
Α	9.95	10.35		
В	2.55	2.95		
С	3.75	4.05		
D	14.95	15.25		
E	3.75	4.25		
F	0.26	0.5		
G	0.68	0.94		
Н	13.3	13.9		
I	4.86	5.26		
J	4.38	4.78		
K	1.14	1.4		
L	2.37	2.79		



YJD117010PG1



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